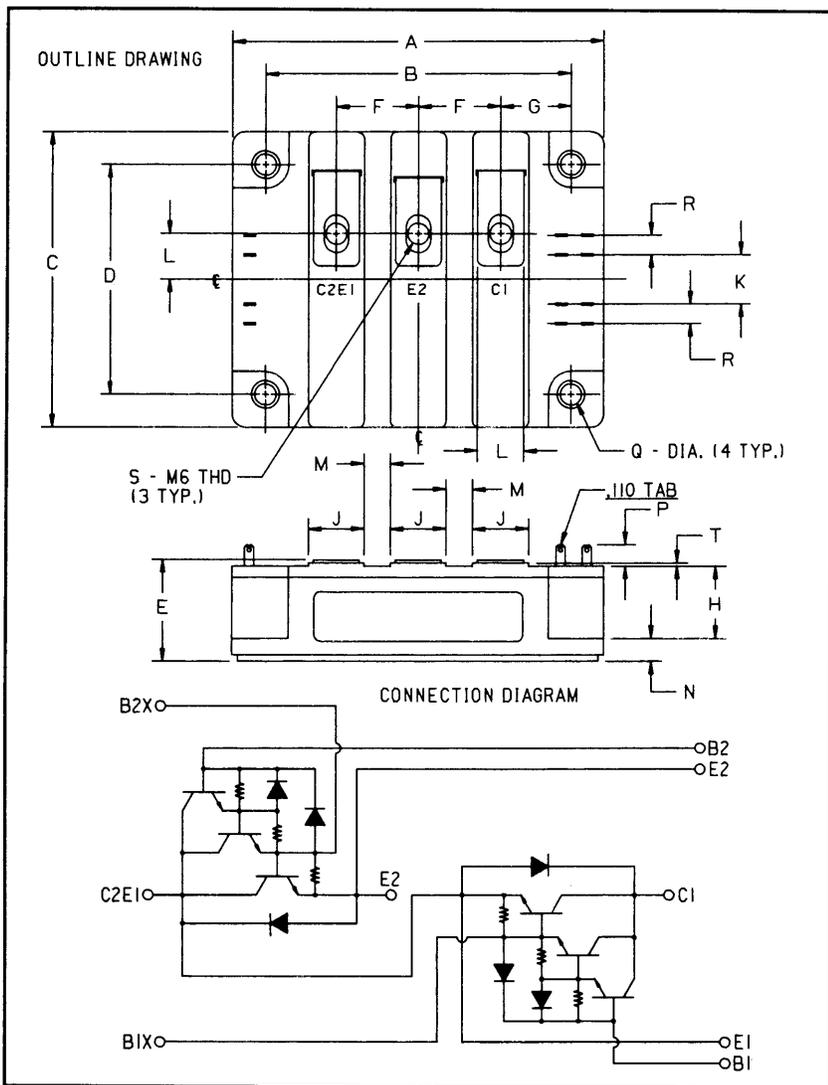


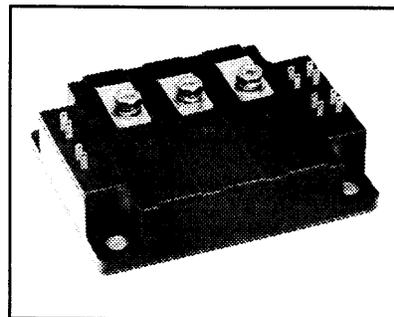
Dual Darlington Transistor Module 200 Amperes/1200 Volts



Outline Drawing

Dimensions	Inches	Millimeters
A	4.449 Max.	113 Max.
B	3.661 ± 0.012	93 ± 0.3
C	3.543 Max.	90 Max.
D	2.756 ± 0.012	70 ± 0.3
E	1.220 Max.	31 Max.
F	0.984	25
G	0.846	21.5
H	0.827	21
J	0.669	17

Dimensions	Inches	Millimeters
K	0.591	15
L	0.551	14
M	0.315	8
N	0.276	7
P	0.256 Min.	6.5 Min.
Q	0.256 dia.	6.5 Dia.
R	0.236	6
S	M6 Metric	M6
T	0.039	1



Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

Features:

- Isolated Mounting
- Planar Chips
- Discrete Fast Recovery Feedback Diode
- High Gain (h_{FE})
- Quick Connect Base-Emitter Signal Terminals
- Base-Emitter Speed-up Diodes

Applications:

- AC Motor Control
- DC Motor Control
- Switching Power Supplies
- Inverters

Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KD621220 is a 1200 Volt, 200 Ampere Dual Darlington Module.

Type	$V_{CE0(sus)}$ Volts (X 100)	Current Rating Amperes (X 10)
KD62	12	20



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD621220
Dual Darlington Transistor Module
200 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KD621220	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	1200	Volts
Collector-Base Voltage	V_{CBO}	1200	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	V_{CEV}	1200	Volts
Continuous Collector Current	I_C	200	Amperes
Diode Forward Current	I_{FM}	200	Amperes
Continuous Base Current	I_B	10	Amperes
Diode Surge Current	I_{FSM}	2000	Amperes
Power Dissipation (Each Transistor)	P_t	1560	Watts
Max. Mounting Torque M6 Terminal Screws	—	26	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	26	in.-lb.
Module Weight (Typical)	—	870	Grams
V Isolation	V_{RMS}	2500	Volts

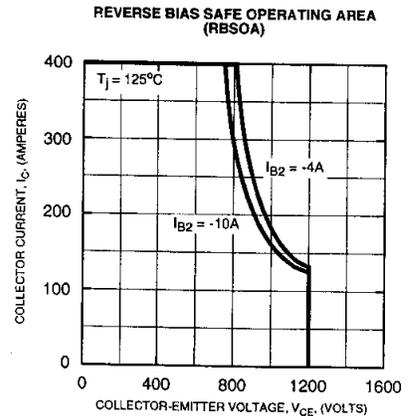
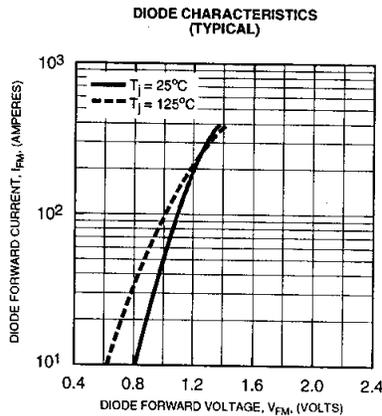
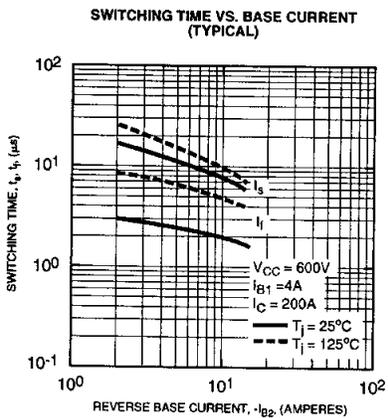
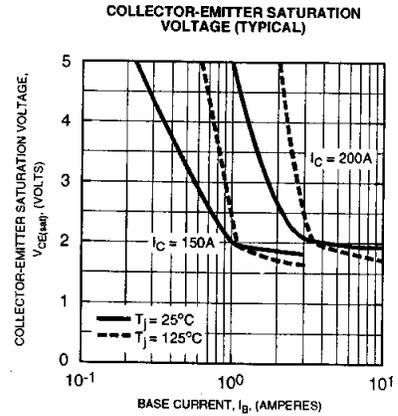
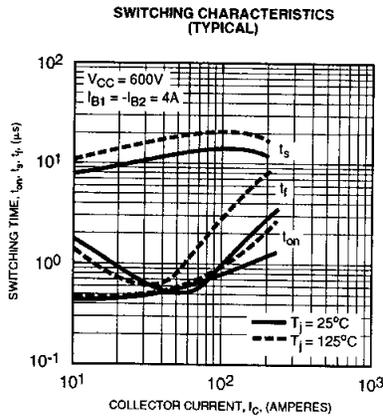
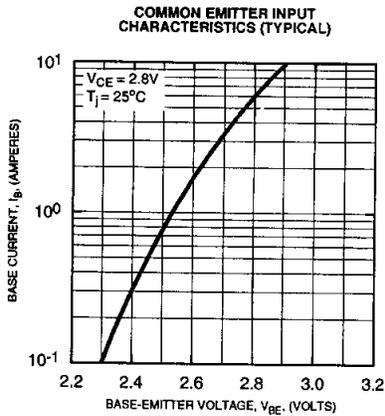
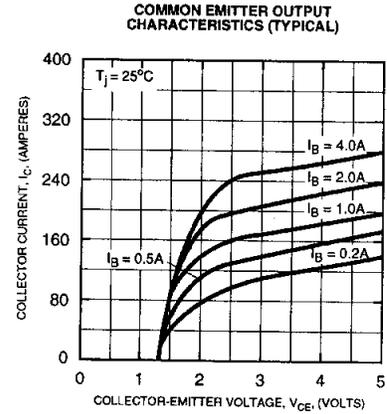
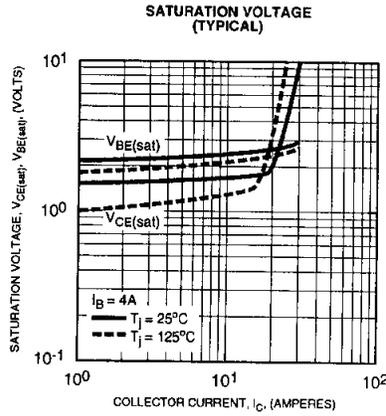
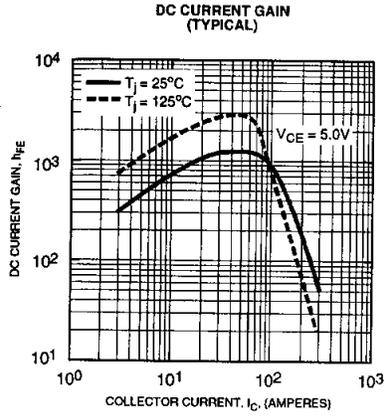
Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Collector Cutoff Current	I_{CEV}	$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}$	—	—	4	mA	
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 7\text{V}$	—	—	800	mA	
DC Current Gain	h_{FE}	$I_C = 200\text{A}, V_{CE} = 5\text{V}$	75	—	—	—	
Diode Forward Voltage	V_{FM}	$I_{FM} = 200\text{A}$	—	—	1.8	Volts	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 200\text{A}, I_B = 4\text{A}$	—	—	3.0	Volts	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 200\text{A}, I_B = 4\text{A}$	—	—	3.5	Volts	
Resistive	Turn-on	t_{on}	$V_{CC} = 600\text{V}$	—	—	3.0	μs
Load	Storage Time	t_s	$I_C = 200\text{A}$	—	—	15	μs
Switch Times	Fall Time	t_f	$I_{B1} = -I_{B2} = 4\text{A}$	—	—	3.0	μs

Thermal and Mechanical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	—	—	0.08	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	—	—	0.35	$^\circ\text{C/W}$

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